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TITLE OF THE INVENTION

Constant Current Circuit and Active Filter Circuit Using the Same

BACKGROUND OF THE INVENTION

Field of the Invention

The present invention relates generally to active filter circuits and more specifically to an active filter circuit driven by a constant current circuit.

Description of the Related Art

A typical active filter circuit includes a Gm-C filter which is driven by a reference current supplied from a constant current source. Usually, the active filter circuit is formed on a common semiconductor substrate. Due to temperature drift or variability of manufacturing process, all resistors of the substrate are uniformly affected so that their resistance values deviate from their rated values. This results in the reference current varying in a direction opposite to the direction of deviation of all resistors. The effect of the varying reference current is combined with a resistance deviation that occurs in the active filter and causes a deviation of its cut-off frequency from the desired frequency.

Japanese Patent Publication 1998-284989 discloses an active filter circuit which includes a temperature-compensation current source as an extra power supply unit of main DC power source. Currents produced by the DC power source and the extra power supply unit are combined to drive a Gm-C filter. By varying the input current of the Gm-C filter according to temperature drift, the cut-off frequency of the filter is kept constant. However, the use of the extra power unit for temperature compensation requires the circuit designer to estimate all possible temperature variations and prepare reference test data based on the estimated temperature variations. The reference test data is used to adjust the output current of the extra power unit corresponding to the estimated temperature variations. While this prior art is satisfactory if the estimated temperature variations are accurate, the disclosed technique is limited for a particular type of filters.

1 Furthermore, the prior art is incapable of compensating for the uniformly  
2 drifted variations of resistors caused by variability of manufacturing process.

3 Japanese Patent Publication 1995-321602 discloses a time-constant  
4 control circuit which forms part of an active filter. The time-constant control  
5 circuit is formed by a pair of transistors and a resistor coupled between the  
6 emitters of the transistors. Two current sources are respectively connected to  
7 the transistors. One of the transistors has its base biased at a reference  
8 voltage. A variability detector is provided for detecting an RC error caused  
9 by variability in the manufacturing process of integrated circuits. Based on  
10 the detected RC error, a control voltage is supplied from the variability  
11 detector to the base of the other transistor and the current sources. The time-  
12 constant control circuit produces a control voltage that renders the  
13 transconductance of the active filter unaffected by the RC error.

14 However, the prior art requires that the variability detector be  
15 implemented with a Gilbert multiplication circuitry which adds to the size  
16 and complexity of the integrated circuit.

#### 17 SUMMARY OF THE INVENTION

18 It is therefore an object of the present invention to provide a simple yet  
19 effective solution for compensating for uniformly drifting variations of  
20 resistors of an active filter circuit formed on a common semiconductor chip,  
21 regardless of varying temperature and variability of manufacturing process.

22 A further object of the present invention is to provide a constant  
23 current circuit which can be universally used with an active filter for  
24 compensating for uniformly drifting variations of resistors of the active filter  
25 and the constant current source formed on a common semiconductor chip.

26 According to one aspect of the present invention, there is provided a  
27 constant current circuit including a plurality of resistors formed on a  
28 semiconductor substrate, comprising a first current source for producing a  
29 first current of constant magnitude regardless of resistance variations which  
30 can occur uniformly in the resistors, and a second current source for

1 producing a second current of magnitude which is inversely variable with the  
2 resistance variations. The first and second current sources are connected to  
3 each other for producing an output current which is equal to a difference  
4 between the first and second currents.

5 According to a second aspect, the present invention provides a  
6 constant current circuit including a plurality of resistors formed on a  
7 semiconductor substrate. The constant current circuit comprises a first group  
8 of parallel transistors having emitters connected via respective resistors to a  
9 voltage source and having collectors connected together to an output  
10 terminal, a second group of parallel transistors having emitters connected via  
11 respective resistors to the voltage source and having collectors connected to  
12 each other, a constant current source connected between the collectors of the  
13 second group of transistors and ground to produce a constant current. The  
14 first and second groups of transistors have their bases connected together to  
15 form a current mirror, whereby a current equal to the constant current is  
16 drawn by the first group of transistors to the output terminal. Transistor-  
17 resistor circuitry is provided for drawing a current inversely variable with  
18 uniform resistance variations of the semiconductor substrate from the output  
19 terminal to ground.

20 According to a third aspect, the present invention provides an active  
21 filter circuit having a plurality of resistors formed on a semiconductor  
22 substrate, comprising a first current source for producing a first current of  
23 constant magnitude regardless of resistance variations which can occur  
24 uniformly in the resistors, a second current source for producing a second  
25 current of magnitude which is inversely variable with the resistance  
26 variations, the first and second current sources being connected to each other  
27 for producing an output current which is equal to a difference between the  
28 first and second currents, and an active filter driven by the output current for  
29 filtering an input signal.

30 According to a fourth aspect, the present invention provides an active

1 filter circuit having a plurality of resistors formed on a semiconductor  
2 substrate. The active filter circuit comprises a first group of parallel  
3 transistors having emitters connected via respective resistors to a voltage  
4 source and having collectors connected together to an output terminal, a  
5 second group of parallel transistors having emitters connected via respective  
6 resistors to the voltage source and having collectors connected to each other,  
7 and a constant current source connected between the collectors of the second  
8 group of transistors and ground to produce a constant current, the first and  
9 second groups of transistors having their bases connected together to form a  
10 current mirror, whereby a current equal to the constant current is drawn by  
11 the first group of transistors to the output terminal. Transistor-resistor  
12 circuitry is provided for drawing a current inversely variable with uniform  
13 resistance variations of the semiconductor substrate from the output terminal  
14 to ground. Further provided are a pair of switching circuits which are driven  
15 by the output current for alternately assuming a conducting state according  
16 to polarity of an input signal, and resistor-capacitor circuitry connected  
17 across the switching circuits to produce a filtered output signal.

#### 18 BRIEF DESCRIPTION OF THE DRAWINGS

19 The present invention will be described in detail further with reference  
20 to the following drawings, in which:

21 Fig. 1 is a circuit diagram of an active filter circuit incorporating a  
22 constant current source of the present invention;

23 Fig. 2 is a circuit diagram of the constant current source constructed  
24 according to a first embodiment of the present invention;

25 Fig. 3 is a circuit diagram of the constant current source constructed  
26 according to a second embodiment of the present invention; and

27 Fig. 4 is a circuit diagram of the constant current source constructed  
28 according to a third embodiment of the present invention.

#### 29 DETAILED DESCRIPTION

30 In Fig. 1, the active filter circuit of the present invention is comprised

1 of a Gm-C filter 10 and a constant current source 11, both of which are  
2 integrated on a common semiconductor substrate 12. Filter 10 includes a pair  
3 of NPN transistors 20 and 21 whose bases are respectively coupled to input  
4 terminals 31 and 32 where an input alternating voltage is applied. The  
5 collectors of transistors 20, 21, which are connected to the voltage source  $V_{cc}$   
6 via current sources 22 and 23, are ac-coupled by a capacitor 30. The collectors  
7 of these transistors 20, 21 are further connected to output terminals 34, 35  
8 from which an output alternating voltage is delivered. The emitters of the  
9 transistors 20, 21 are dc-coupled by a resistor 33 and further connected to the  
10 collectors of NPN transistors 24, 25, respectively. The bases of transistors 24,  
11 25 are connected to a circuit node 36 and the emitters of transistors 24, 25 are  
12 connected to ground via respective resistors 26, 27.

13 Constant current source 11 of the present invention, which is  
14 connected between the voltage source  $V_{cc}$  and ground, includes current  
15 sources 40 and 41 and a drive circuit 42 which drives the current sources 40  
16 and 41. A circuit node between the current sources 40 and 41 is connected to  
17 an output terminal 43 from which an output current  $I_{out}$  is supplied to the  
18 circuit node 36 of the active filter 10.

19 Details of the constant current source 11 of a first embodiment of the  
20 present invention are shown in Fig. 2. In this embodiment, the drive circuit  
21 42 drives the current source 40 with a current  $I \times N$  and drives the current  
22 source 41 with a current  $I \times N/M$ , where  $M$  is the number of collector-  
23 coupled PNP transistors provided in each of the current source 40 and the  
24 drive circuit 42 that form a current mirror and  $N$  is the number of transistors  
25 provided in the current source 41 that forms part of the current mirror. In the  
26 present invention,  $N$  and  $M$  are assumed to be 1 and 2, respectively.

27 Current source 40 comprises a pair of PNP transistors 50, 51 whose  
28 emitters are respectively connected via resistors 52, 53 to the voltage source  
29  $V_{cc}$  and whose collectors connected together to the output terminal 43. Drive  
30 circuit 42 comprises a pair of PNP transistors 70, 71 whose emitters are

1 respectively connected via resistors 72, 73 to the voltage source  $V_{cc}$  and  
2 whose collectors are connected together to a current source 74 and to the base  
3 of a PNP transistor 75 whose emitter is connected to the bases of transistors  
4 70, 71 and whose collector is connected to ground through a resistor 76.

5 Current source 74 is formed of resistors. These resistors are provided  
6 external to the semiconductor substrate 12 so that current source 74 can  
7 deliver a constant current " $I$ ", regardless of temperature drift or variability of  
8 manufacturing processes which would uniformly affect the resistivity of all  
9 the internally provided resistors of the substrate 12.

10 The bases of PNP transistors 50, 51 of current source 40 and the bases  
11 of transistors 70, 71 of driver 42 are connected together to form a current  
12 mirror and the PNP transistor 60 forms part of the current mirror by coupling  
13 its base to the bases of transistors 50, 51, 70, 71. As a result of the current  
14 mirror relation, the same current  $I$  is caused to flow through the collector-  
15 coupled PNP transistors 50, 51 of current source 40 to the output terminal 43  
16 as the current  $I$  drawn through the collector-coupled PNP transistors 70, 71  
17 by the constant current source 74 to ground.

18 Current source 41 is of a  $V_{BE}$ -dependent type. Current source 41  
19 includes a PNP transistor 60 whose base is connected to the bases of  
20 transistors 50, 51, 70, 71. The emitter of transistor 60 is connected to the  
21 voltage source  $V_{cc}$  via a resistor 61 and its collector is connected to a circuit  
22 node N1 to which the base of an NPN transistor 62 and the collector of an  
23 NPN transistor 63 are connected. The emitter of transistor 62 and the base of  
24 transistor 63 are connected together to a circuit node N2 which is grounded  
25 via a resistor 65. The collector of transistor 62 is connected to the output  
26 terminal 43. The emitter of transistor 63 is connected to ground via a resistor  
27 64.

28 In the current source 41, the PNP transistor 60 draws a current from  
29 the voltage source  $V_{cc}$  to ground via transistor 63 and resistor 64. Since the  
30 number of PNP transistors provided in the current source 41 is  $1/2$  of the

1 PNP transistors of each half of the current mirror circuit, the current that  
2 flows through the node N1 is one-half of the current I.

3 NPN transistors 62 and 63 cause a current  $I_1$  to flow from the output  
4 terminal 43 to ground through resistor 65. This current is given by Equation  
5 (1).

$$6 \quad I_1 = \frac{V_{N2}}{R_5} \quad (1)$$

7 where,  $V_{N2}$  is the potential at the circuit node N2 and  $R_5$  is the value of  
8 resistor 65. Since the potential  $V_{N2}$  is expressed as follows:

$$9 \quad V_N = V_{BE} + \frac{N}{M} I \times R_4 \quad (2)$$

10 Since  $N = 1$  and  $M = 2$ , Equation (2) is rewritten as:

$$11 \quad V_{N2} = V_{BE} + \frac{1}{2} I \times R_4 \quad (3)$$

12 where,  $V_{BE}$  is the base-emitter voltage of transistor 63 and  $R_4$  is the value of  
13 resistor 64. Current  $I_1$  is thus given by Equation (4).

$$14 \quad I_1 = \frac{V_{BE} + \frac{1}{2} I \times R_4}{R_5} \quad (4)$$

15 Since the output current  $I_{out}$  is equal to the difference between I and  $I_1$ , the  
16 following relation holds:

$$17 \quad I_{out} = I - I_1 = I - \frac{V_{BE} + \frac{1}{2} I \times R_4}{R_5} \quad (5)$$

18 When the current  $I_{out}$  is supplied to the node 36 of active filter 10, the  
19 NPN transistors 24 and 25 are turned ON. If an input alternating voltage is  
20 applied to the terminals 34 and 35, the NPN transistors 20 and 21 are turned  
21 ON and OFF in a complementary fashion depending on the polarity of the  
22 input voltage. As a result, when the transistor 20 is ON, it draws a current  
23 from the current source 22 to ground through transistor 24 and resistor 26,  
24 and when the transistor 21 is ON, it draws a current from the current source

1 23 to ground through transistor 25 and resistor 27.

2 If the input voltage is a low frequency signal, the capacitor 30  
3 functions as a high impedance element and its presence can be ignored.  
4 Hence, the output terminals 34 and 35 are in an open circuit condition,  
5 causing an alternating voltage to appear thereacross. If the input voltage is a  
6 high frequency signal, the capacitor 30 functions as a low impedance element.  
7 Hence, the output terminals 34 and 35 are in a short-circuit condition, causing  
8 no output voltage to appear thereacross. In this way, the active filter 10  
9 operates as a low-pass filter. The cut-off frequency  $f_c$  of the low-pass filter is  
10 given by Equation (6).

$$11 \quad f_c = \frac{1}{2\pi \sqrt{C \times \frac{1}{g_m}}} \quad (6)$$

$$12 \quad g_m = \frac{1}{R + \frac{2 \times V_{cc}}{I_{out}}} \quad (7)$$

13 where C is the capacitance of capacitor 30, R is the value of resistor 33, and  
14  $V_{cc}$  is the power voltage of the voltage source Vcc.

15 Current  $I_1$  of Equation (4) varies inversely with resistance variations  
16 which can occur uniformly in all internal resistors of the semiconductor  
17 substrate 12 as follows.

18 If the temperature of semiconductor substrate 12 rises, all resistors on  
19 the substrate 12 increase uniformly, and the current  $I_1$  of current source 41  
20 decreases, while current I of current source 74 remains unaffected due to the  
21 provision of resistors external to the substrate 12. Because of the current  
22 mirror relation to the drive circuit 42, the current I drained through the  
23 current source 40 to the output terminal 43 is also unaffected. Therefore, the  
24 output current  $I_{out}$  increases as seen from Equation (5). This increase would  
25 cause the transconductance  $g_m$  to decrease. However, Equation (7) shows  
26 that a concomitant increase in the resistance R (of resistor 33) produces an



1 opposing effect on this decrease. On the other hand, if the temperature of  
2 substrate 12 lowers, all of its resistors decrease uniformly and the current  $I_1$   
3 increases while the output current  $I_{out}$  decreases, tending to increase the  
4 transconductance. A concomitant decrease in the resistance  $R$  counteracts  
5 this increase in transconductance. If the resistance  $R$  is appropriately  
6 determined in relation to the output current  $I_{out}$ , such temperature-  
7 dependent mutual-conductance variations can be completely nullified, so  
8 that the cut-off frequency  $f_c$  can be maintained constant under a varying  
9 temperature.

10 Active filter 10 and the constant current source 11 cooperate in much  
11 the same way when all the internal resistors of the substrate 12 are caused to  
12 offset uniformly from their nominal values due to variability of  
13 manufacturing processes.

14 The present invention thus eliminates the need to prepare reference  
15 measurement data for circuit testing. Therefore, the constant current source  
16 11 of the present invention can be universally used with various active filters.

17 A constant current source 11A, shown in Fig. 3, is a second  
18 embodiment of the present invention. This embodiment differs from the  
19 previous embodiment in that it replaces the  $V_{BE}$ -dependent type current  
20 source 41 with a  $V_{CC}$ -dependent type current source 41A.

21 Current source 41A includes an NPN transistor 81 whose collector is  
22 connected to the output terminal 43. The base of transistor 81 is connected to  
23 a circuit node N3 of resistors 82 and 83 connected in series between  $V_{cc}$  and  
24 ground. Transistor 81 has its emitter coupled to ground through a resistor 84.  
25 The potential at node N3 is given by Equation (8) and the transistor 81 draws  
26 a current  $I_2$  from the output terminal 43 to ground. Current  $I_2$  is given by  
27 Equation (9).

28 
$$V_{N3} = \frac{R_{13}}{R_{12} + R_{13}} \times V_{cc} \quad (8)$$

1 
$$I_2 = \frac{V_{N3} - V_{BE}}{R_{14}} = \frac{R_{13} \times V_{cc}}{(R_{12} + R_{13})R_{14}} - \frac{V_{BE}}{R_{14}} \quad (9)$$

2 where,  $R_{12}$ ,  $R_{13}$  and  $R_{14}$  represent the resistances of resistors 82, 83 and 84,  
3 respectively, and  $V_{BE}$  is the base-emitter voltage of transistor 81. Therefore,  
4 the output current  $I_{out}$  is obtained as follows:

5 
$$I_{out} = I - I_2 = I - \left\{ \frac{R_{13} \times V_{cc}}{(R_{12} + R_{13})R_{14}} - \frac{V_{BE}}{R_{14}} \right\} \quad (10)$$

6 It is seen from Equations (9) and (10) that when all resistors of the  
7 substrate 12 uniformly increase, current  $I_2$  decreases and output current  $I_{out}$   
8 increases, and when all resistors uniformly decrease, current  $I_2$  increases and  
9 output current  $I_{out}$  decreases. The cut-off frequency of the filter 10 is thus  
10 maintained constant.

11 A constant current source 11B, shown in Fig. 4, is a third embodiment  
12 of the present invention, which differs from the first embodiment in that it  
13 replaces the  $V_{BE}$ -dependent type current source 41 with a band-gap type  
14 current source 41B.

15 Current source 41B includes a pair of PNP transistors 90 and 91 having  
16 their base connected to the bases of current-mirror transistors 50, 51, 70, 71,  
17 and having their emitters connected to  $V_{cc}$  via resistors 92 and 93. The  
18 collector of transistor 90 is connected to the collectors of a group G of "n"  
19 parallel transistors of NPN conductivity, while the collector of transistor 91 is  
20 coupled to a circuit node N5 to which the collector of an NPN transistor 94  
21 are also connected.

22 The emitters of transistor group G are connected together to a point  
23 which is connected through resistors 96 and 97 to ground, while the emitter of  
24 transistor 94 is connected to a circuit node N4 which is formed between the  
25 resistors 96 and 97. Current source 41B further includes an NPN transistor 95  
26 whose collector is connected to the output terminal 43, its emitter being  
27 coupled through a resistor 99 to ground. The bases of transistors 94, 95 and

1 transistor group G are connected together to the circuit node N5. PNP  
 2 transistors 90 and 91 constitute a current mirror with the PNP transistors 50,  
 3 51, 70 and 71. Since the PNP transistors 90 and 91 have their collectors not  
 4 coupled together unlike transistors 50, 51 and 70, 71, one-half of the current I  
 5 is drawn through each of the transistors 90 and 91 to the circuit node N4,  
 6 where these currents are summed to produce a current I through the resistor  
 7 97. Therefore, the potentials  $V_{N4}$  and  $V_{N5}$  at the circuit nodes N4 and N5 are  
 8 given by Equations (11) and (12), respectively.

$$9 \quad V_{N4} = I \times R_{17} \quad (11)$$

$$10 \quad V_{N5} = V_{N4} + V_{BE} = V_{N4} + \frac{I \times R_{16}}{2} + V_{GBE} \quad (12)$$

11 where,  $R_{16}$  and  $R_{17}$  are the respective resistances of resistors 96 and 97,  $V_{BE}$  is  
 12 the base-emitter voltage of transistor 94 and  $V_{GBE}$  is the base-emitter voltage  
 13 of the transistor group G.

14 According to bipolar transistor theory,  $V_{GBE}$  of the "n" transistors  
 15 connected in parallel to transistor 94, is given by Equation (13).

$$16 \quad V_{GBE} = V_{BE} - V_T \times \ln(n) \quad (13)$$

17 where,  $V_T$  is the volt equivalent of temperature which is expressed as:

$$18 \quad V_T = \frac{k \times T}{q} \quad (14)$$

19 where k is the Boltzmann constant, T is the absolute temperature (Kelvin) and  
 20 q is the electric charge. From Equations (12) and (13), the voltage developed  
 21 across the resistor 96 is equal to:

$$22 \quad \frac{1}{2} I \times R_{16} = V_{BE} - V_{GBE} = V_T \times \ln(n) \quad (15)$$

23 Hence, the potentials  $V_{N4}$  and  $V_{N5}$  are given by Equations (16) and (17),  
 24 respectively.

$$25 \quad V_{N4} = \{2 \times V_T \times \ln(n)\} \times \frac{R_{17}}{R_{16}} \quad (16)$$

1 
$$V_{N5} = V_{BE} + \{2 \times V_T \times \ln(n)\} \times \frac{R_{17}}{R_{16}} \quad (17)$$

2 The first term of Equation (17), i.e.,  $V_{BE}$  indicates that the potential  $V_{N5}$   
3 varies with a negative temperature characteristic and the second term, i.e.,  $\{2$   
4  $\times V_T \times \ln(n)\}$  indicates that it varies with a positive temperature  
5 characteristic, which counteracts the negative temperature characteristic of  
6 the first term. The potential  $V_{N5}$  at the circuit node N5 is thus kept constant  
7 regardless of temperature variations. Since current  $I_3$ , which is drawn by  
8 transistor 95 to pass through resistor 99 to ground, is given by:

9 
$$I_3 = \frac{V_{N5} - V_{BE}}{R_{19}} \quad (18)$$

10 (where,  $V_{BE}$  is the base-emitter voltage of transistor 95 and  $R_{19}$  is the value of  
11 resistor 99), the output current  $I_{out}$  of Fig. 4 becomes:

12 
$$I_{out} = I - I_3 = I - \frac{V_{N5} - V_{BE}}{R_{19}} \quad (19)$$

13 It is seen from Equations (18) and (19) that current  $I_3$  varies inversely  
14 with resistance variations and the output current  $I_{out}$  varies with the  
15 resistance variations.